# Old Company Name in Catalogs and Other Documents

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April 1<sup>st</sup>, 2010 Renesas Electronics Corporation

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# MOS FIELD EFFECT TRANSISTOR $\mu$ PA2451B

# N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

### **DESCRIPTION**

The  $\mu$  PA2451B is a switching device, which can be driven directly by a 2.5 V power source.

The  $\mu$  PA2451B features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

### **FEATURES**

- 2.5 V drive available
- · Low on-state resistance

 $R_{DS(on)1}$  = 20.0 m $\Omega$  MAX. (Vgs = 4.5 V, ID = 4.0 A)

 $R_{DS(on)2} = 21.0 \text{ m}\Omega \text{ MAX.} \text{ (V}_{GS} = 4.0 \text{ V}, I_{D} = 4.0 \text{ A})$ 

 $R_{DS(on)3} = 25.0 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = 3.1 \text{ V, Ip} = 4.0 \text{ A)}$ 

 $R_{DS(on)4} = 32.0 \text{ m}\Omega \text{ MAX.} \text{ (Vgs = 2.5 V, ID = 4.0 A)}$ 

· Built-in G-S protection diode against ESD

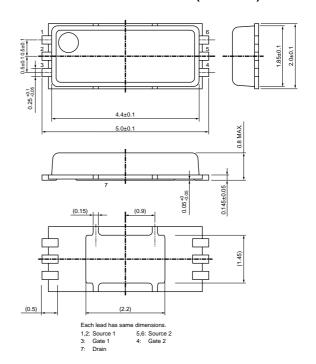
# ORDERING INFORMATION

PART NUMBER	PACKAGE
μ PA2451BTL	6PIN HWSON (4521)

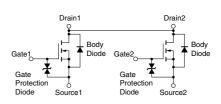
# ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (V <sub>GS</sub> = 0 V)	Voss	30.0	V
Gate to Source Voltage (VDS = 0 V)	Vgss	±12.0	V
Drain Current (DC) Note1	ID(DC)	±8.2	Α
Drain Current (pulse) Note2	I <sub>D(pulse)</sub>	±65.0	Α
Total Power Dissipation (2 units) Note1	P <sub>T1</sub>	2.5	W
Total Power Dissipation (2 units) Note3	P <sub>T2</sub>	0.7	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

### PACKAGE DRAWING (Unit: mm)



# **EQUIVALENT CIRCUIT**



- Notes 1. Mounted on ceramic board of 50 cm<sup>2</sup> x 1.1 mm
  - **2.** PW  $\leq$  10  $\mu$ s, Duty Cycle  $\leq$  1%
  - 3. Mounted on FR-4 board of 50 cm<sup>2</sup> x 1.1 mm

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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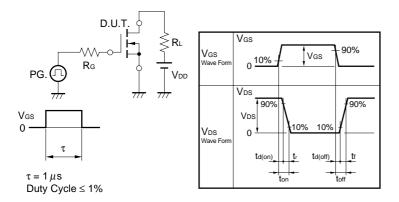
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# **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

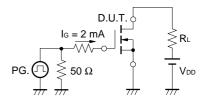
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 30.0 V, V <sub>GS</sub> = 0 V			1.0	μА
Gate Leakage Current	Igss	$V_{GS} = \pm 12.0 \text{ V}, V_{DS} = 0 \text{ V}$			±10.0	μΑ
Gate Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 1.0 mA	0.50		1.50	V
Forward Transfer Admittance Note	y <sub>fs</sub>	V <sub>DS</sub> = 10.0 V, I <sub>D</sub> = 4.0 A	3.5			S
Drain to Source On-state Resistance Note	RDS(on)1	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 4.0 A	12.0	15.0	20.0	mΩ
	RDS(on)2	V <sub>GS</sub> = 4.0 V, I <sub>D</sub> = 4.0 A	12.5	15.5	21.0	mΩ
	RDS(on)3	V <sub>GS</sub> = 3.1 V, I <sub>D</sub> = 4.0 A	14.0	17.5	25.0	mΩ
	RDS(on)4	V <sub>GS</sub> = 2.5 V, I <sub>D</sub> = 4.0 A	15.5	22.0	32.0	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> = 10.0 V		540		pF
Output Capacitance	Coss	V <sub>GS</sub> = 0 V		100		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		70		pF
Turn-on Delay Time	<b>t</b> d(on)	V <sub>DD</sub> = 15.0 V, I <sub>D</sub> = 4.0 A		20		ns
Rise Time	<b>t</b> r	V <sub>GS</sub> = 4.0 V		80		ns
Turn-off Delay Time	<b>t</b> d(off)	R <sub>G</sub> = 6 Ω		131		ns
Fall Time	tr			89		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 24.0 V		9.2		nC
Gate to Source Charge	Qgs	V <sub>GS</sub> = 4.0 V		1.7		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 8.2 A		4.1		nC
Body Diode Forward Voltage Note	V <sub>F(S-D)</sub>	I <sub>F</sub> = 8.2 A, V <sub>GS</sub> = 0 V		0.83		V
Reverse Recovery Time	trr	IF = 8.2 A, VGS = 0 V		64		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		36		nC

**Note** Pulsed: PW  $\leq$  350  $\mu$ s, Duty Cycle  $\leq$  2%

# **TEST CIRCUIT 1 SWITCHING TIME**

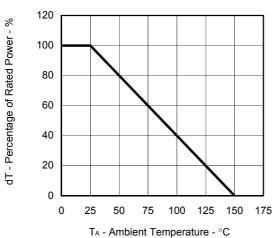


# TEST CIRCUIT 2 GATE CHARGE

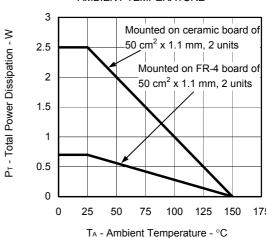


# **ELECTRICAL CHARACTERISTICS (TA = 25°C)**

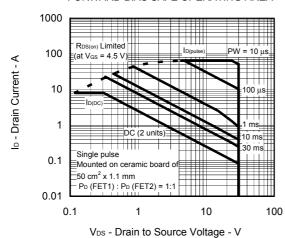
# DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



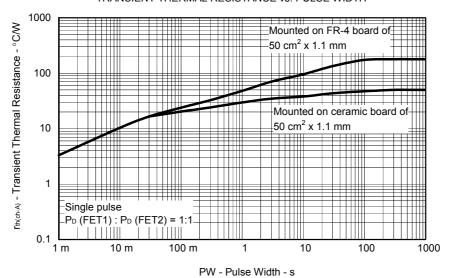
# TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



### FORWARD BIAS SAFE OPERATING AREA



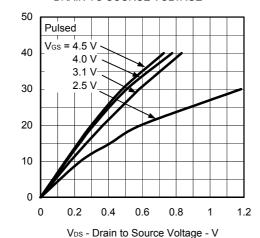
# TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH



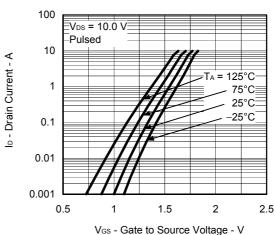
3

Ip - Drain Current - A

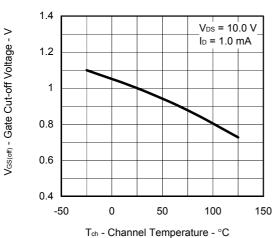
#### DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



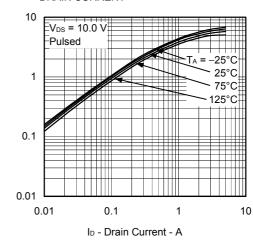
### FORWARD TRANSFER CHARACTERISTICS



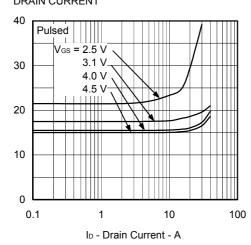
### GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



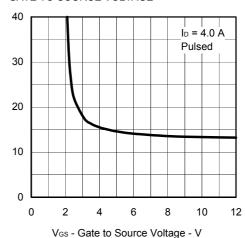
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



V<sub>GS</sub> - Gate to Source Voltage - V

RDS(on) - Drain to Source On-state Resistance - mΩ

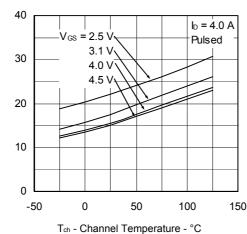
| y<sub>fs</sub> | - Forward Transfer Admittance - S

R<sub>DS(on)</sub> - Drain to Source On-state Resistance - mΩ

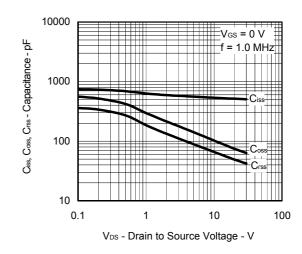
 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$  - Drain to Source On-state Resistance -  $m\Omega$ 

td(on), tr, td(off), tr - Switching Time - ns

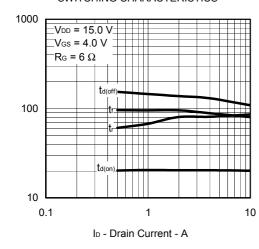




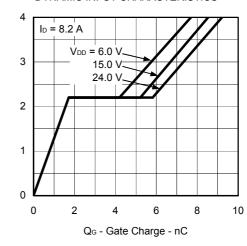
### CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



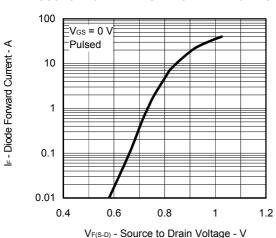
### SWITCHING CHARACTERISTICS



DYNAMIC INPUT CHARACTERISTICS



### SOURCE TO DRAIN DIODE FORWARD VOLTAGE



5

Vos - Gate to Drain Voltage - V

NEC  $\mu$  PA2451E

## <Notes for using this device safely>

When you use this device, in order to prevent a customer's hazard and damage, use it with understanding the following contents. If used exceeding recommended conditions, there is a possibility of causing failure of the device and characteristic degradation.

- 1. When you mount the device on a substrate, carry out within our recommended soldering conditions of infrared reflow. If mounted exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
- 2. When you wash the device mounted the substrate, carry out within our recommended conditions. If washed exceeding the conditions, the characteristic of a device may be degraded and it may result in failure.
- 3. When you use ultrasonic wave to substrate after the device mounting, prevent from touching a resonance generator directly. If it touches, the characteristic of a device may be degraded and it may result in failure.
- 4. Please refer to **Figure 1** as an example of the land pattern. Optimize the land pattern in consideration of density, appearance of solder fillets, common difference, etc in an actual design.

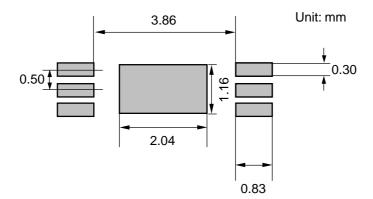


Figure 1. Example of the land pattern

5. This device is very thin device and should be handled with caution for mechanical stress. The rate of distortion applied to the device should become below 2000  $\mu\epsilon$ . Note1 If the rate of distortion exceeds 2000  $\mu\epsilon$ , the characteristic of a device may be degraded and it may result in failure.

### Figure 2. Direction of substrate and stress

The substrate that mounted the device is on a stand with a support width of 24 mm.

The device is turned downward. The stress is applied from a top.

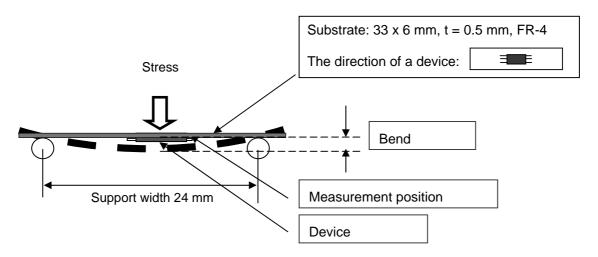
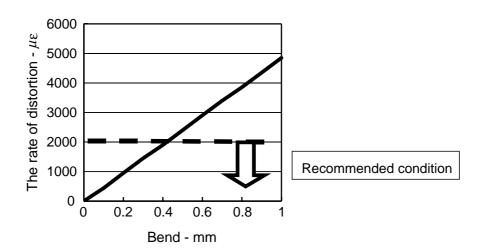


Figure 3. Example of the bend and the rate of distortion Note2



**Note 1.** Definition of rate of distortion (written as  $\varepsilon$  in this document)

- $\varepsilon = (I I_0)/I_0$
- lo: Distance for two arbitrary points before receiving stress.
- I: Distance above-mentioned when receiving stress.
- **2.** The relation of the distortion and the bend changes with several conditions, such as a size of substrate and so on.

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NEC  $\mu$  PA2451B

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